L Number	Hits	Search Text	DB	Time stamp
-	2	(("6297168") or ("6383943")).PN.	USPAT; US-PGPUB	2003/01/27 14:02
-	883	(BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/04/21 18:45
-	169	((BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) near3 (conformal or via or opening or trench or groove or sidewall)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/04/18 17:10
-	94	(((BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) near3 (conformal or via or opening or trench or groove or sidewall)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) same etch$3 near2 stop$4	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/04/18 17:12
	75	((((BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) near3 (conformal or via or opening or trench or groove or sidewall)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) same etch$3 near2 stop$4) and (BARC or ARC or antireflect$4 or anti adj reflect$4) same (silicon adj oxynitride or "SiON" or titanium adj nitride or "Ti.sub."?"N.sub."? or "TiN" or "Ti" adj "N")	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/04/21 16:17
	19	((((BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) near3 (conformal or via or opening or trench or groove or sidewall)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) same etch$3 near2 stop$4) not (((((BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) near3 (conformal or via or opening or trench or groove or sidewall)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) same etch$3 near2 stop$4) and (BARC or ARC or antireflect$4 or anti adj reflect$4) same (silicon adj oxynitride or "SiON" or titanium adj nitride or "Ti.sub."?"N.sub."? or "TiN" or "Ti" adj "N"))	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/04/18 17:45
-	75	(((BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) near3 (conformal or via or opening or trench or groove or sidewall)) not ((((BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) near3 (conformal or via or opening or trench or groove or sidewall)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) same etch$3 near2 stop$4)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/04/18 17:45

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-	714	((BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric)) not (((BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric)) and (BARC or ARC or antireflect$4 or anti adj reflect$4) near3 (conformal or via or opening or trench or groove or sidewall))	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/04/18 17:46
-	42789	(BARC or ARC or antireflect$4 or anti adj reflect$4) with (via or hole or wall or sidewall or opening or trench)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/04/21 10:18
-	9	((BARC or ARC or antireflect$4 or anti adj reflect$4) with (via or hole or wall or sidewall or opening or trench)) and 427/97.ccls.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/04/21 10:19
-	1	("6541367").PN.	USPAT; US-PGPUB	2003/04/21 16:17
-	0	430/311,313,317,950.ccls. and (DARC or TARC or BARC or ARC or antireflect$4 or anti adj reflect$4) near5 (sidewall or side adj wall or hole adj wall or via near2 wall or via near2 side or trench near2 wall or trench near2 side or conformal$3) same (IMD or ILD or dielectric) not ((BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric).)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/04/21 18:55
-	0	430/311,313,317,950.ccls. and (DARC or TARC or BARC or ARC or antireflect$4 or anti adj reflect$4) near5 (sidewall or side adj wall or hole adj wall or via near2 wall or via near2 side or trench near2 wall or trench near2 side or conformal$3) and (IMD or ILD or dielectric) not ((BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric))	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/04/21 18:58
-	0	(430/311,313,317,950.ccls. and (DARC or TARC or BARC or ARC or antireflect$4 or anti adj reflect$4) near5 (sidewall or side adj wall or hole adj wall or via near2 wall or via near2 side or trench near2 wall or trench near2 side or conformal$3) and (IMD or ILD or dielectric)) not ((BARC or ARC or antireflect$4 or anti adj reflect$4) same (resist or photoresist) same (IMD or dielectric))	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/04/21 18:59

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